Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	al:
Glass	
Overall Length:	
Between 0.120 inc	ches and 0.200 inches
Terminal Length:	
1.500 inches	
Overall Diameter	:
Between 0.055 inc	ches and 0.090 inches
Function For Wh	ich Designed:
Voltage regulator	
Mounting Method	d:
Terminal	
Features Provide	ed:
Hermetically seale	ed case and quality assurance level txv
Semiconductor M	Naterial:
Silicon	
Voltage Rating Ir	Nolts Per Characteristic:
12.0 regulator vo	ltage
Voltage Toleranc	e In Percent:
-5.0/+5.0	
Current Rating P	er Characteristic:
35.00 milliampere	s repetitive peak forward current
Power Rating Pe	r Characteristic:
500.0 milliwatts sr	nall-signal input power, common-collector preset
Maximum Operat	ting Tempurature Per Measurement Point:
175.0 degrees cel	sius ambient air
Test Data Docum	nent:
81349-mil-s-1950	0 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; excludes	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	d performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type A	nd Quantity:
2 uninsulated wire	lead
Specification Dat	ta:
81349-mil-s-1950	0/127 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	